

# PC733

AC Input Type **Photocoupler**

\* Lead forming type (I type) is also available. (PC733I) (page 656)

## ■ Features

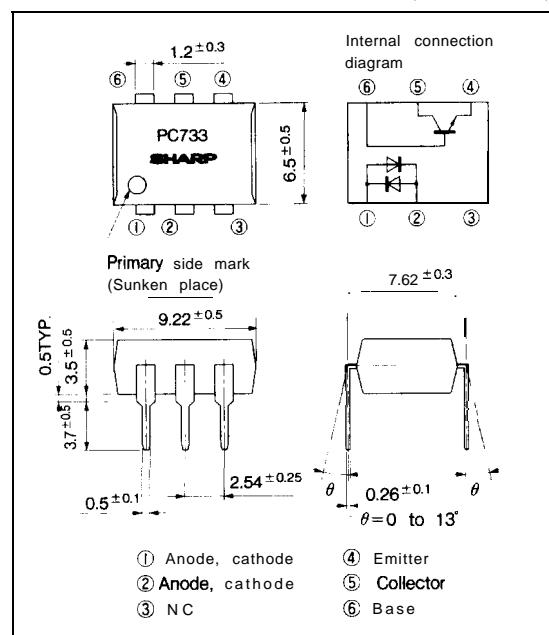
1. AC input response
2. High isolation voltage between input and output ( $V_{IS}$ : 5 000V<sub>rms</sub>)
3. Current transfer ratio  
CTR : MIN. 15% at IF=  $\pm 1$ mA, V<sub>CE</sub>=5V
4. Low collector dark current  
(I<sub>CEO</sub> : MAX. 10<sup>-7</sup>A at V<sub>CE</sub>= 20V)
5. TTL compatible output
6. Recognized by UL, file No. E64380

## ■ Applications

1. Telephone sets
2. Programmable controllers
3. System appliances, measuring instruments
4. Signal transmission between circuits of different potentials and impedances

## ■ Outline Dimensions

(Unit : mm)



## ■ Absolute Maximum Ratings

(Ta = 25°C )

	Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	±50	mA
	*1 Peak forward current	I <sub>FM</sub>	±1	A
	Power dissipation	P	70	mW
output	Collector -emitter voltage	V <sub>CEO</sub>	35	v
	Emitter-collector voltage	V <sub>ECO</sub>	6	v
	Collector -base voltage	V <sub>CBO</sub>	35	v
	Emitter -base voltage	V <sub>EBO</sub>	6	v
	Collector current	I <sub>C</sub>	50	mA
	Collector power dissipation	P <sub>C</sub>	150	mW
	Total power dissipation	P <sub>tot</sub>	170	mW
	*1 Isolation voltage	V <sub>iso</sub>	5000	V <sub>rms</sub>
	Operating temperature	T <sub>opr</sub>	-25 to +100	°C
	Storage temperature	T <sub>stg</sub>	-40 to +125	°C
	Soldering temperature	T <sub>sol</sub>	260	°C

\*1 Pulse width ≤ 100 μs, Duty ratio= 0.001

\*2 40 to 60 %RH, AC for 1 minute

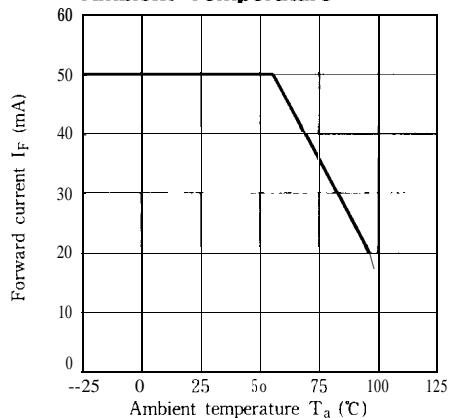
\*3 For 10 seconds

## ■ Electro-optical Characteristics

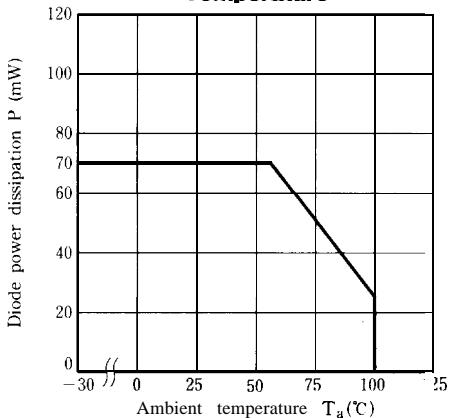
(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> =±20mA		1.2	1.4	V
	Peak forward voltage	V <sub>FM</sub>	I <sub>FM</sub> =±0.5A		—	3.0	V
	Terminal capacitance	C <sub>t</sub>	V=0, f=1kHz	—	50	400	pF
output	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> =20V, I <sub>F</sub> =0, R <sub>BE</sub> =∞			10 <sup>-7</sup>	A
Transfer characteristics	Current transfer ratio	CTR	I <sub>F</sub> =±1mA, V <sub>CE</sub> =5V, R <sub>BE</sub> =∞	15	—	300	%
	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>F</sub> =±20mA, I <sub>C</sub> =1mA, R <sub>RE</sub> =∞	—	0.1	0.2	V
	Isolation resistance	R <sub>ISO</sub>	DC500V, 40 to 60%RH	5×10 <sup>10</sup>	10 <sup>11</sup>	—	Ω
	Floating capacitance	C <sub>f</sub>	V=0, f=1MHz	—	0.6	1.0	pF
	Cut-off frequency	f <sub>c</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA, R <sub>L</sub> =100Ω, R <sub>BE</sub> =∞, -3dB	15	80	—	kHz
	Response time	t <sub>r</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =2mA	—	4	18	μs
	Fall time	t <sub>f</sub>	R <sub>L</sub> =100Ω, R <sub>BE</sub> =∞		3	18	μs

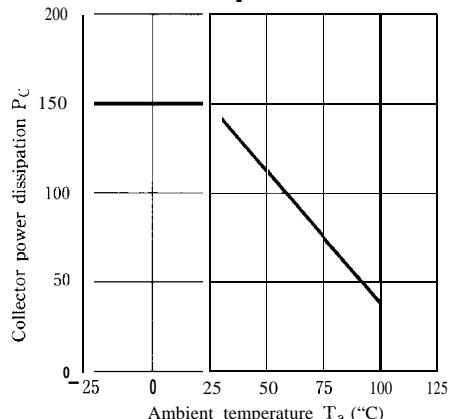
**Fig. 1 Forward Current vs. Ambient Temperature**



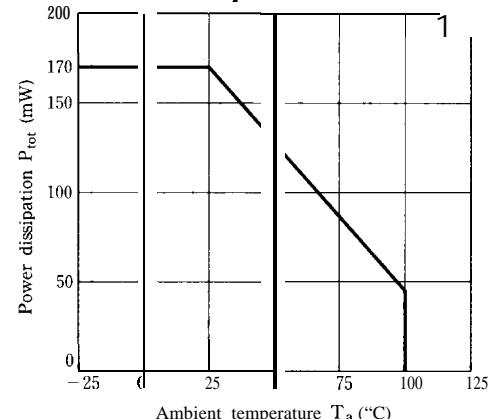
**Fig. 2 Diode Power Dissipation v.s. Ambient Temperature**

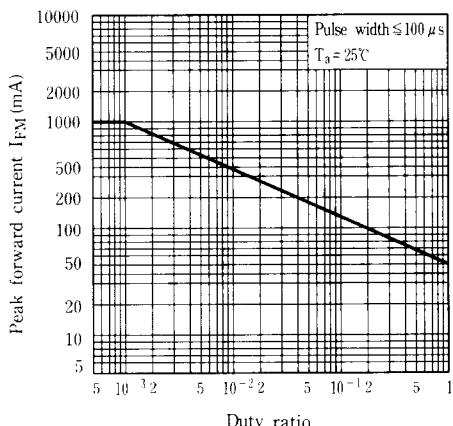
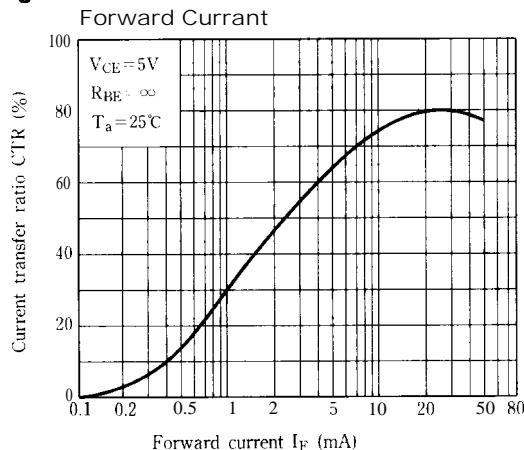
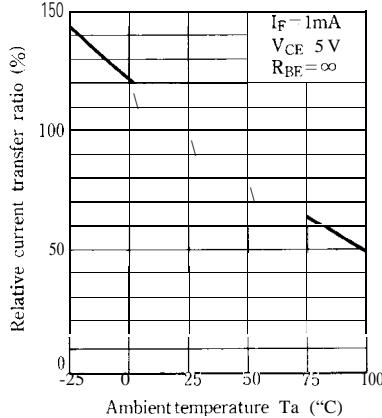
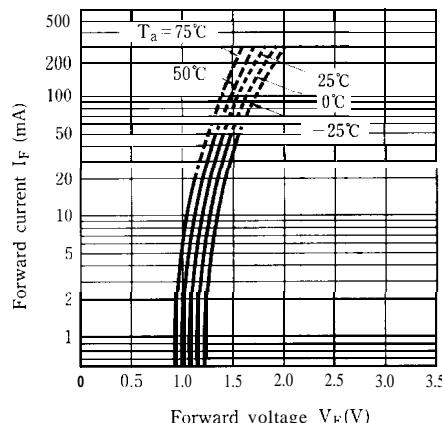
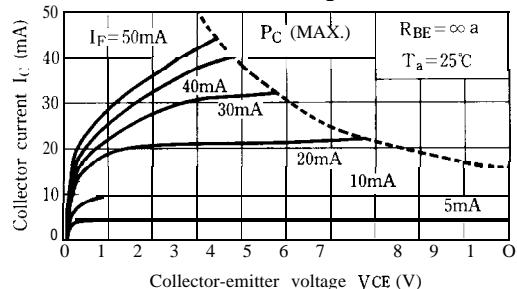


**Fig. 3 Collector Power Dissipation VS. Ambient Temperature**

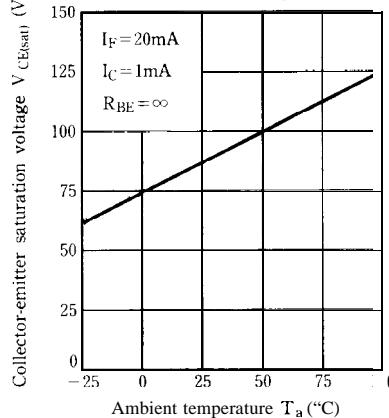


**Fig. 4 Power Dissipation vs. Ambient Temperature**

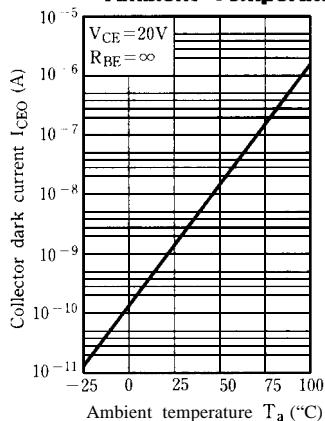


**Fig. 5 Peak Forward Current vs. Duty Ratio****Fig. 7 Current Transfer Ratio vs. Forward Current****Fig. 9 Relative Current Transfer Ratio vs. Ambient Temperature****Fig. 6 Forward Current vs. Forward Voltage****Fig. 8 Collector Current vs. Collector-emitter Voltage**

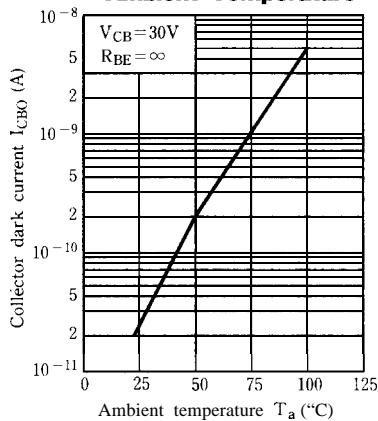
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**Fig. 10 Collector-emitter Saturation Voltage vs. Ambient Temperature**

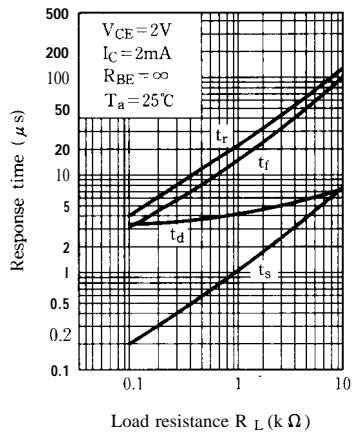
**Fig.11-a Collector Dark Current vs. Ambient Temperature**



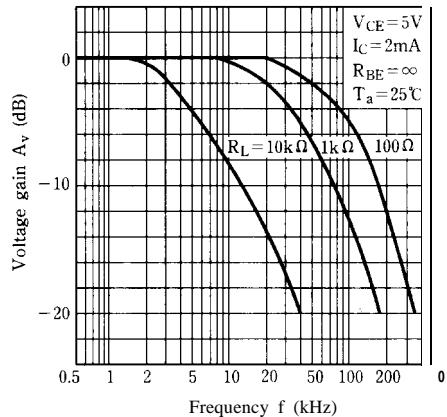
**Fig.11-b Collector-base Dark Current vs. Ambient Temperature**



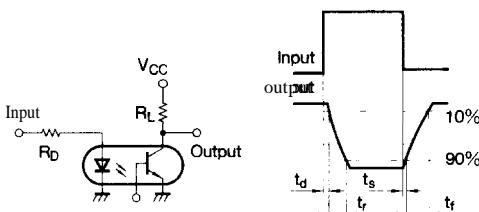
**Fig.12 Response Time vs. Load Resistance**



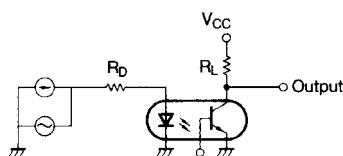
**Fig.13 Frequency Response**



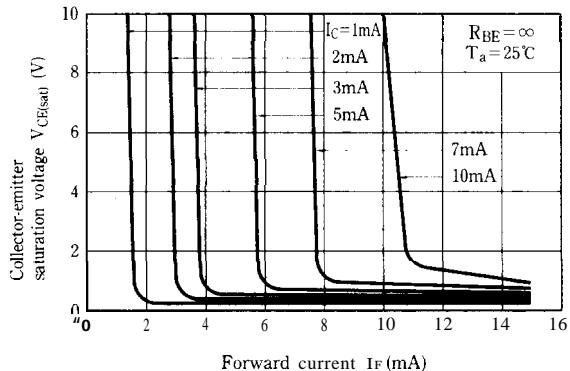
**Test Circuit for Response Time**



**Test Circuit for Frequency Response**



**Fig.14 Collector-emitter Saturation Voltage vs. Forward Current**



- Please refer to the chapter "Precautions for Use" (Page 78 to 93)